Cascadable Amplifier 10 to 1200 MHz

Features

- LOW NOISE: 3.5 dB (TYP.)
- HIGH EFFICIENCY: 15 mA (TYP.) @ +5 Volts
- GOOD DYNAMIC RANGE: 102.5 dB (TYP.) in 1 MHz BW
- LOW VSWR: <1.5:1 (TYP.)

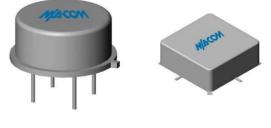
Description

The A16-2 RF amplifier is a discrete thin film hybrid design, which incorporates the use of thin film manufacturing processes for accurate performance and high reliability.

This single stage bipolar transistor feedback amplifier design displays impressive performance over a broadband frequency range. An active DC biasing network is used for temperature-stable performance, in addition to an RF Choke, used for power supply decoupling.

Both TO-8 and Surface Mount packages are hermetically sealed,

and MIL-STD-883 environmental screening is available.





Ordering Information

Part Number	Package	
MAAM-008198-00A162	TO-8	
MAAM-008198-SMA162	Surface Mount	
MAAM-008198-0CA162	SMA Connectorized **	

** The connectorized version is not RoHs compliant.

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МАСОМ

Rev. V4



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Electrical Specifications: $Z_0 = 50\Omega$, $V_{CC} = +5 V_{DC}$

Deventer	Unite	Typical	Guaranteed	
Parameter	Units	Units 25°C	0° to 50°C	-54º to +85ºC*
Frequency	MHz	5-1300	10-1200	10-1200
Small Signal Gain (min)	dB	13.0	12.0	11.5
Gain Flatness (max)	dB	±0.2	±0.5	±0.7
Reverse Isolation	dB	16		
Noise Figure (max)	dB	3.5	4.0	4.5
Power Output @ 1 dB comp. (min)	dBm	6.0	5.0	4.5
IP3	dBm	+18		
IP2	dBm	+28		
Second Order Harmonic IP	dBm	+34		
VSWR Input / Output (max)		1.5:1 / 1.5:1	2.2:1 / 2.2:1	2.3:1 / 2.3:1
DC Current @ 15 Volts (max)	mA	15	17	18

Absolute Maximum Ratings

Parameter	Absolute Maximum	
Storage Temperature	-62°C to +125°C	
Case Temperature	+125°C	
DC Voltage	+8 V	
Continuous Input Power	+13 dBm	
Short Term Input power (1 minute max.)	50 mW	
Peak Power (3 µsec max.)	0.5 W	
"S" Series Burn-In Temperature (case)	+125°C	

Thermal Data: V_{CC} = +5 V_{DC}

Parameter	Rating
Thermal Resistance θ_{jc}	45°C/W
Transistor Power Dissipation P_d	0.051 W
Junction Temperature Rise Above Case T _{jc}	+2°C

* Over temperature performance limits for part number CA16-2, guaranteed from 0°C to +50°C only.

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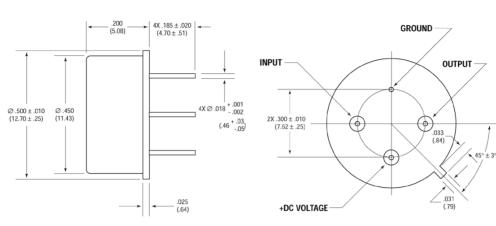
Outline Drawing: TO-8 *



.350

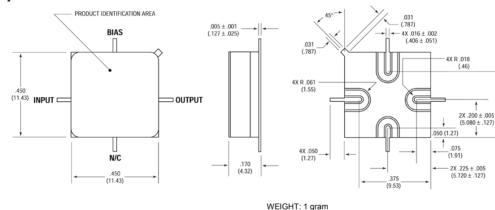
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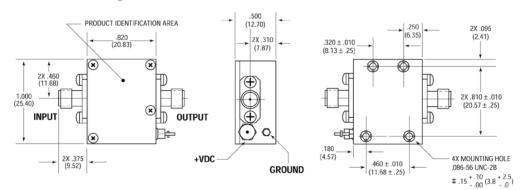


WEIGHT: 1 gram (0.04 oz.) max

Outline Drawing: Surface Mount



Outline Drawing: SMA Connectorized



WEIGHT: 19 grams (0.67 oz.) max

* Dimensions are inches (millimeters) ±0.015 (0.38) unless otherwise specified.

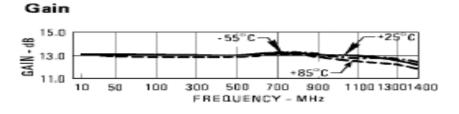
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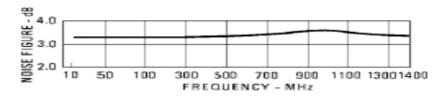
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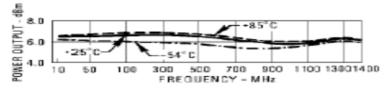
Typical Performance Curves at +25°C



Noise Figure

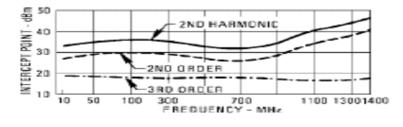


Power Output*

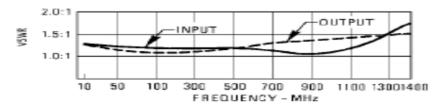


* at 1 dB Gain Compression

Intercept Point







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